## Photoreflector

# P5587, P5588

### Photo IC output (digital) photoreflectors

P5587 and P5588 are photoreflectors combining a high power infrared LED and low voltage photo IC. The photo IC consists of a high sensitivity photodiode, amplifier, schmitt trigger circuit, and output phototransistor, etc. on a single chip.

#### **Features**

- Miniature package
- Low voltage operation
- Photo IC, open collector output
- P5587: "H" level output at light input P5588: "L" level output at light input

### Applications

- Paper detection in copiers and printers, etc.
- Tape end detection in VTRs, tape recorders, etc.

■ Absolute maximum ratings (Ta=25 °C)

Parameter		Symbol	Value	Unit
Input (LED)	Forward current	lF	50	mA
	Reverse voltage	VR Max.	5	V
	Power dissipation	Р	80	mW
	Supply voltage	Vcc	-0.5 to +7	V
	Output voltage	Vo	-0.5 to +7	V
	Output current	Ю	8	mA
	Power dissipation	Р	80	mW
Operating temperature		Topr	-25 to +85	°C
Storage temperature		Tstg	-30 to +85	°C
Soldering		-	260 °C, 3 s, refer to Dimensional outline	-

■ Electrical and optical characteristics (Ta=25 °C, Vcc=5 V, unless otherwise noted)

Parameter		Symbol	Condition	P5587			P5588			Unit
				Min.	Тур.	Max.	Min.	Тур.	Max.	Offic
Input (LED)	Forward voltage	VF	IF=20 mA	ı	1.23	1.45	1	1.23	1.45	V
	Reverse current	lr	VR=5 V	1	-	10	-	-	10	μΑ
	Terminal capacitance	Ct	V=0 V, f=1 MHz	ı	30	-	ı	30	-	рF
Output (photo IC)	Supply voltage	Vcc		2.2	-	7	2.2	-	7	V
	Low level output voltage	Vol	IoL=4 mA *1	ı	0.1	0.4	ı	0.1	0.4	V
	High level output current	Іон	Vo=5 V *2	1	-	10	1	-	10	μA
	Current consumption	lcc		ı	1.3	3.0	1	1.3	3.0	mΑ
Transfer characteristics	L→H Threshold input current	IFLH	RL=1.2 kΩ, d=3 mm Reflecting surface: white paper (reflectivity 90 % or more)	-	-	10	-	-	-	mA
	H→L Threshold input current	IFHL		-	-	-	-	-	10	mA
	Hysterisis	-	*3	ı	0.8	-	ı	0.8	-	-
	L→H Propagation delay time	tPLH	IF=15 mA RL=1.2 kΩ d=3 mm	-	-	20	-	-	30	μs
	H→L Propagation delay time	tphl		-	-	30	-	-	20	μs
	Rise time	tr		ı	0.07	-	Ī	0.07	-	μs
	Fall time	tf		-	0.03	-	-	0.03	-	μs

\*1: P5587: IF=0 mA, P5588: IF=15 mA

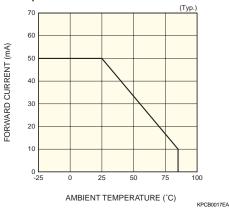
\*2: P5587: IF=15 mA, P5588: IF=0 mA

\*3: P5587: IFHL/IFLH, P5588: IFLH/IFHL

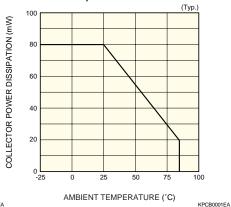
Note) Connect a  $0.01\,\mu F$  capacitor or larger between Vcc and GND.



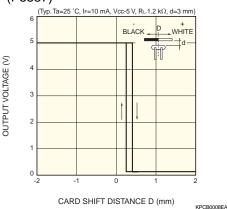
#### ■ LED forward current vs. ambient temperature



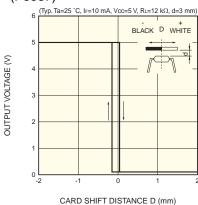
#### ■ Photo IC power dissipation vs. ambient temperature



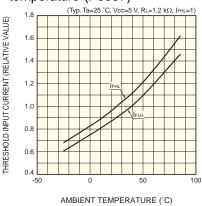
#### ■ Position detection characteristic (P5587)



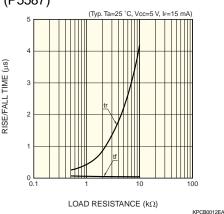
#### ■ Position detection characteristic (P5587)



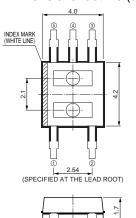
■ Threshold input current vs. ambient ■ Rise/fall time vs. load resistance temperature (P5587)



(P5587)



■ Dimensional outline (unit: mm)

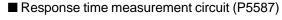


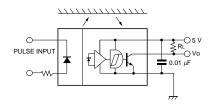
① CATHODE ② ANODE ③ Vo ④ GND ⑤ Vcc

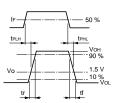
0~13 SOLDER THE LEADS AT A POINT BELOW THIS POSITION

noted: ±0.2 Shaded area indicates burr.

 $5.6 \pm 0.3$ 







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